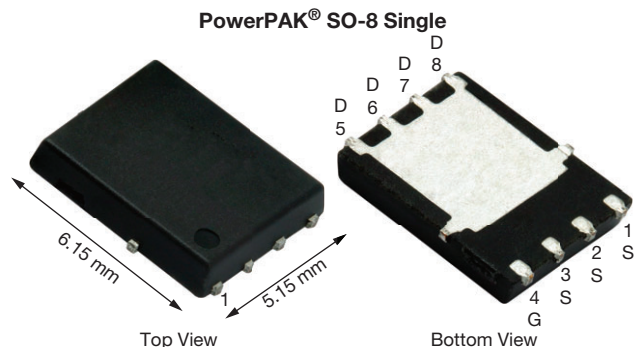


P-Channel 60 V (D-S) MOSFET



PRODUCT SUMMARY	
V_{DS} (V)	-60
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -10$ V	0.007
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.012
Q_g typ. (nC)	31.7
I_D (A) ^a	-90.9
Configuration	Single

ORDERING INFORMATION	
Package	PowerPAK SO-8
Lead (Pb)-free and halogen-free	SiR5607DP-T1-RE3
Lead (Pb)-free, halogen-free, BLR and IOL	SiR5607DP-T1-UE3

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage	V_{DS}	-60	V	
Gate-source voltage	V_{GS}	+20 / -20		
Continuous drain current ($T_J = 150$ °C)	$T_C = 25$ °C	-90.9	A	
	$T_C = 70$ °C	-72.7		
	$T_A = 25$ °C	-22.2 ^{b, c}		
	$T_A = 70$ °C	17.8 ^{b, c}		
Pulsed drain current ($t = 100$ μ s)	I_{DM}	-250		
Continuous source-drain diode current	$T_C = 25$ °C	-94.6		
	$T_A = 25$ °C	-5.7 ^{b, c}		
Single pulse avalanche current	I_{AS}	-50		
Single pulse avalanche energy	E_{AS}	125	mJ	
Maximum power dissipation	$T_C = 25$ °C	104	W	
	$T_C = 70$ °C	66.6		
	$T_A = 25$ °C	6.25 ^{b, c}		
	$T_A = 70$ °C	4 ^{b, c}		
Operating junction and storage temperature range	T_J, T_{stg}	-55 to +150	°C	
Soldering recommendations (peak temperature) ^{d, e}		260		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^b	$t \leq 10$ s	R_{thJA}	15	20	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	0.9	1.2	

Notes

- $T_C = 25$ °C
- Surface mounted on 1" x 1" FR4 board
- $t = 10$ s
- See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
- Maximum under steady state conditions is 54 °C/W

FEATURES

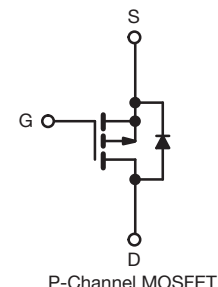
- TrenchFET® Gen V p-channel power MOSFET
- Very low $R_{DS(on)}$ minimizes voltage drop and reduces conduction loss
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Adapter and charger switch
- Battery and circuit protection
- OR-ing
- Load switch
- Motor drive control





SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = -250 μA	-60	-	-	V
V _{DS} temperature coefficient	ΔV _{DS} /T _J	I _D = -10 mA	-	-34	-	mV/°C
V _{GS(th)} temperature coefficient	ΔV _{GS(th)} /T _J	I _D = -250 μA	-	5.1	-	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250 μA	-1.4	-	-2.6	V
Gate-source leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = +20 / -20 V	-	-	100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = -60 V, V _{GS} = 0 V	-	-	-10	μA
		V _{DS} = -60 V, V _{GS} = 0 V, T _J = 70 °C	-	-	-50	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -10 V, I _D = -20 A	-	0.0056	0.007	Ω
		V _{GS} = -4.5 V, I _D = -20 A	-	0.0092	0.012	
Forward transconductance ^a	g _{fs}	V _{DS} = -15 V, I _D = -20 A	-	52	-	S
Dynamic ^b						
Input capacitance	C _{iss}	V _{DS} = -30 V, V _{GS} = 0 V, f = 1 MHz	-	5020	-	pF
Output capacitance	C _{oss}		-	2050	-	
Reverse transfer capacitance	C _{rss}		-	85	-	
Total gate charge	Q _g	V _{DS} = -30 V, V _{GS} = -10 V, I _D = -20 A	-	74	112	nC
Gate-source charge	Q _{gs}	V _{DS} = -30 V, V _{GS} = -4.5 V, I _D = -20 A	-	34.8	53	
Gate-drain charge	Q _{gd}		-	18	-	
Gate resistance	R _g		-	10.1	-	
Gate resistance	R _g	f = 1 MHz	0.5	1.4	2.4	Ω
Turn-on delay time	t _{d(on)}	V _{DD} = -30 V, R _L = 1.5 Ω, I _D ≅ -20 A, V _{GEN} = -10 V, R _g = 1 Ω	-	18	36	ns
Rise time	t _r		-	9	18	
Turn-off delay time	t _{d(off)}		-	40	80	
Fall time	t _f		-	9	18	
Turn-on delay time	t _{d(on)}	V _{DD} = -30 V, R _L = 1.5 Ω, I _D ≅ -20 A, V _{GEN} = -4.5 V, R _g = 1 Ω	-	45	90	
Rise time	t _r		-	320	640	
Turn-off delay time	t _{d(off)}		-	30	60	
Fall time	t _f		-	20	40	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I _S	T _C = 25 °C	-	-	-94.6	A
Pulse diode forward current	I _{SM}		-	-	-250	
Body diode voltage	V _{SD}	I _S = -5 A, V _{GS} = 0 V	-	-0.76	-1.1	V
Body diode reverse recovery time	t _{rr}	I _F = -20 A, di/dt = 100 A/μs, T _J = 25 °C	-	70	140	ns
Body diode reverse recovery charge	Q _{rr}		-	85	170	nC
Reverse recovery fall time	t _a		-	36	-	ns
Reverse recovery rise time	t _b		-	34	-	

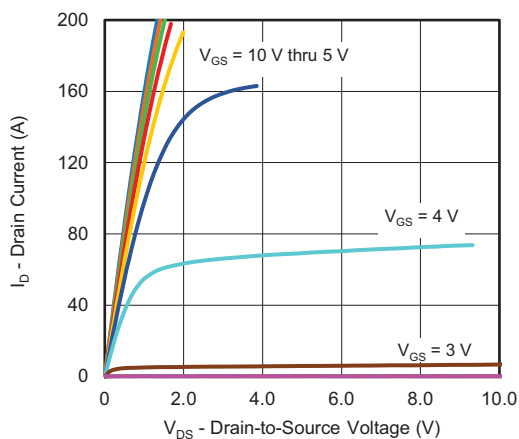
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing

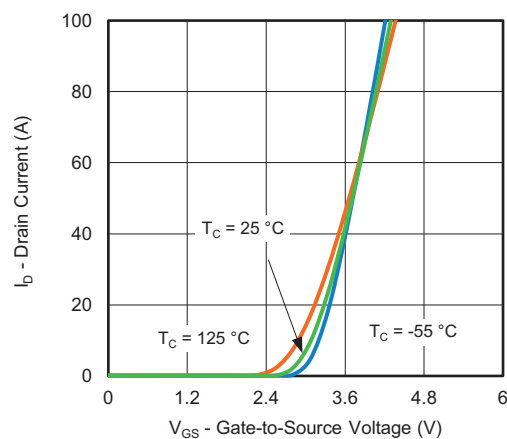
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



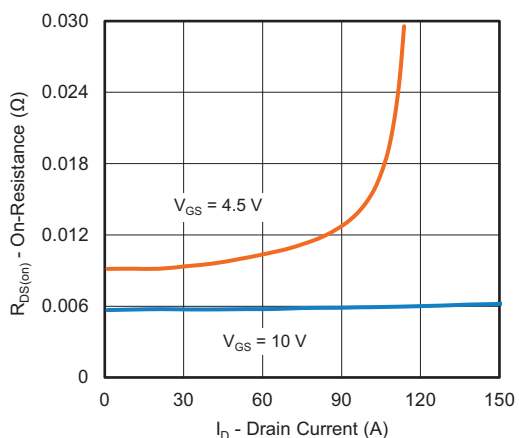
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



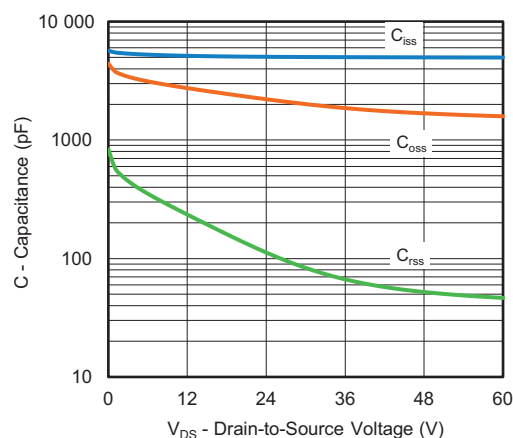
Output Characteristics



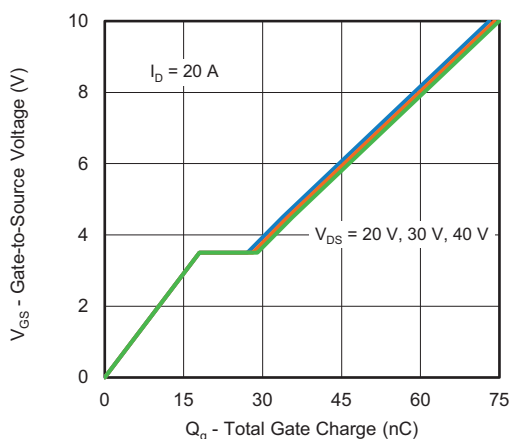
Transfer Characteristics



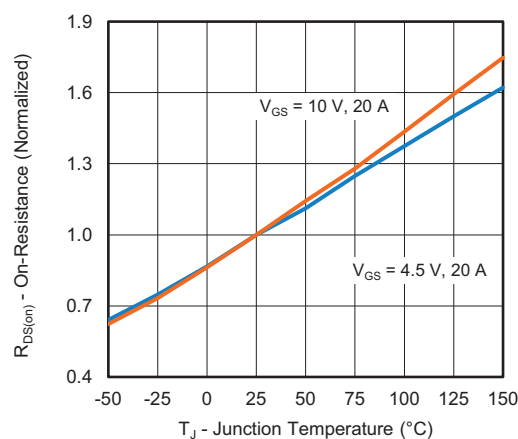
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



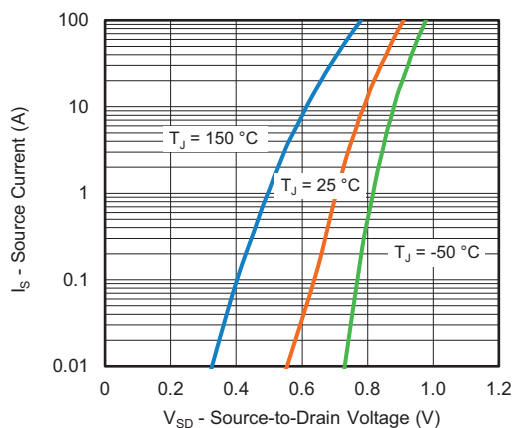
Gate Charge



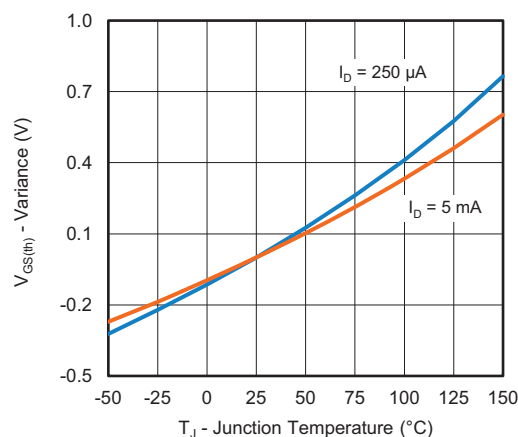
On-Resistance vs. Junction Temperature



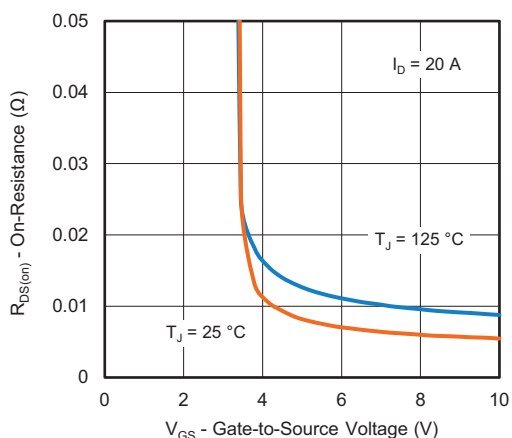
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



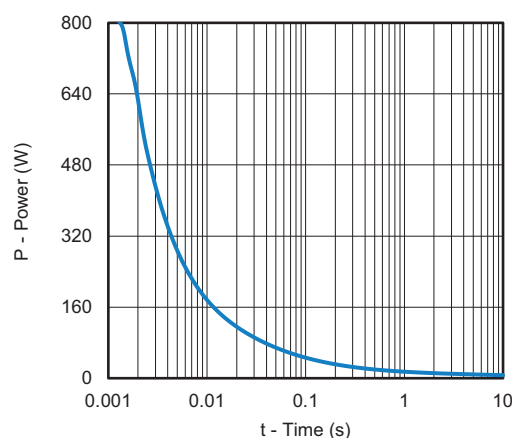
Source-Drain Diode Forward Voltage



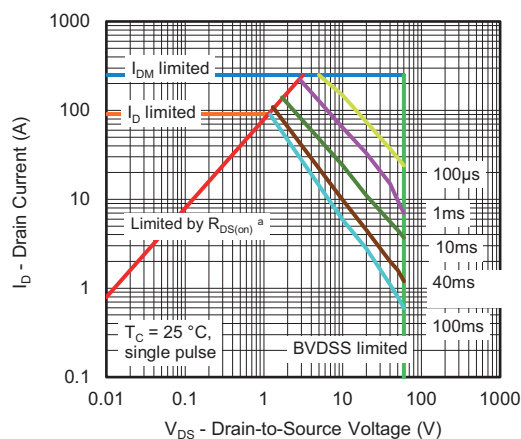
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient



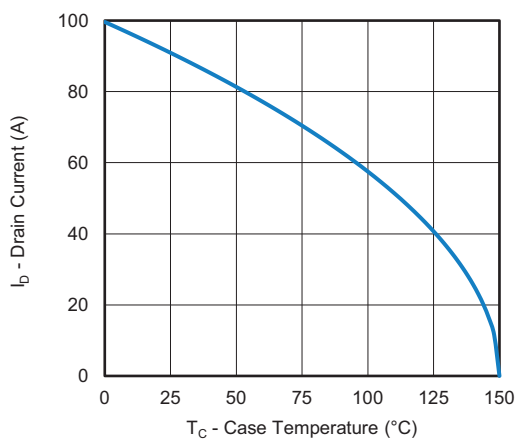
Safe Operating Area, Junction-to-Case

Note

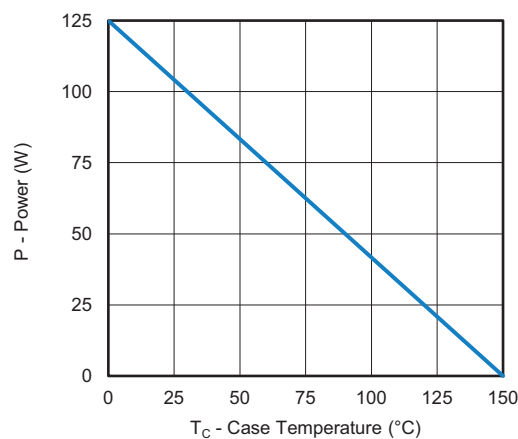
a. $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Current Derating ^a



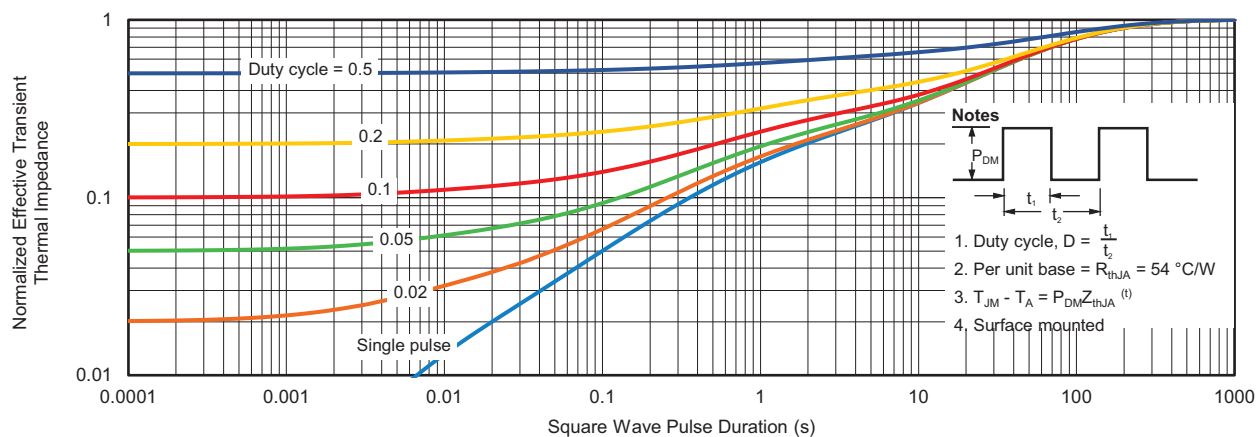
Power, Junction-to-Case

Note

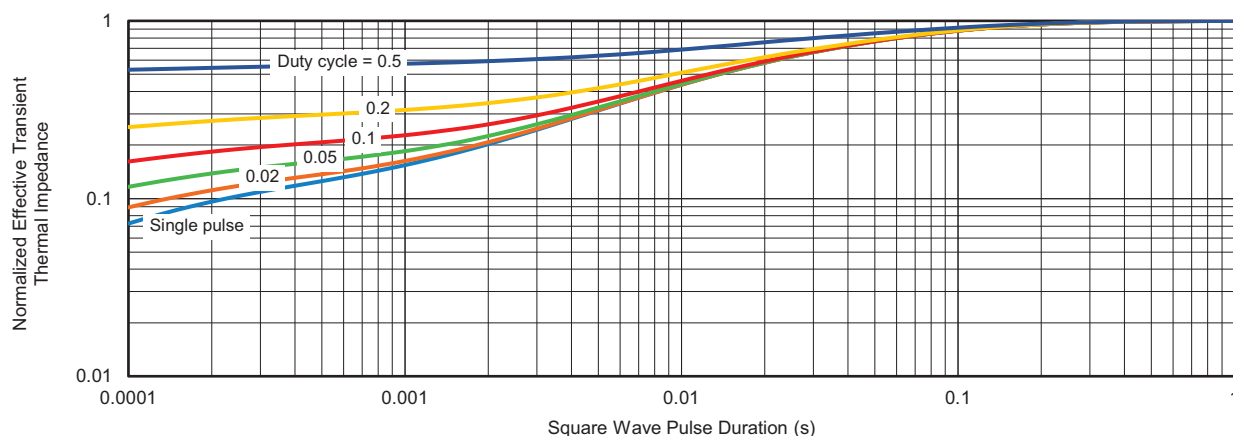
- a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62247.

PowerPAK® SO-8, (Single/Dual)



DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.97	1.04	1.12	0.038	0.041	0.044
A1		-	0.05	0	-	0.002
b	0.33	0.41	0.51	0.013	0.016	0.020
c	0.23	0.28	0.33	0.009	0.011	0.013
D	5.05	5.15	5.26	0.199	0.203	0.207
D1	4.80	4.90	5.00	0.189	0.193	0.197
D2	3.56	3.76	3.91	0.140	0.148	0.154
D3	1.32	1.50	1.68	0.052	0.059	0.066
D4	0.57 typ.			0.0225 typ.		
D5	3.98 typ.			0.157 typ.		
E	6.05	6.15	6.25	0.238	0.242	0.246
E1	5.79	5.89	5.99	0.228	0.232	0.236
E2	3.48	3.66	3.84	0.137	0.144	0.151
E3	3.68	3.78	3.91	0.145	0.149	0.154
E4	0.75 typ.			0.030 typ.		
e	1.27 BSC			0.050 BSC		
K	1.27 typ.			0.050 typ.		
K1	0.56	-	-	0.022	-	-
H	0.51	0.61	0.71	0.020	0.024	0.028
L	0.51	0.61	0.71	0.020	0.024	0.028
L1	0.06	0.13	0.20	0.002	0.005	0.008
θ	0°	-	12°	0°	-	12°
W	0.15	0.25	0.36	0.006	0.010	0.014
M	0.125 typ.			0.005 typ.		
ECN: S17-0173-Rev. L, 13-Feb-17						
DWG: 5881						

RECOMMENDED MINIMUM PADS FOR PowerPAK® SO-8 Single



Recommended Minimum Pads
Dimensions in Inches/(mm)

[Return to Index](#)



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Vishay products are not designed for use in life-saving or life-sustaining applications or any application in which the failure of the Vishay product could result in personal injury or death unless specifically qualified in writing by Vishay. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.